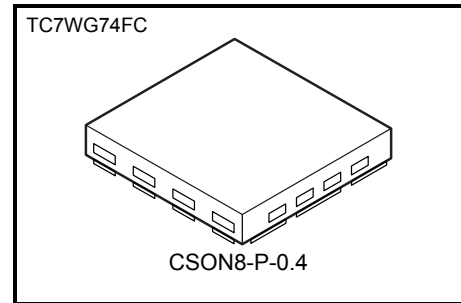


# TC7WG74FC

## D-Type Flip Flop with Preset and Clear

### Features

- High-speed :  $f_{MAX} = 246 \text{ MHz (Typ.)}$   
at  $V_{CC} = 3 \text{ V, CL}=15\text{pF}$
- High-level output current: :  $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$   
at  $V_{CC} = 3 \text{ V}$
- Operation voltage range :  $V_{CC(opr)}=0.9\sim 3.6\text{V}$
- 5.5-V tolerant inputs
- 3.6-V power down protection outputs



Weight: 0.002g (typ.)

### Absolute Maximum Ratings ( Ta = 25°C )

Characteristics	Symbol	Value	Unit
Power supply voltage	$V_{CC}$	-0.5~4.6	V
DC input voltage	$V_{IN}$	-0.5~7.0	V
DC output voltage	$V_{OUT}$	-0.5~4.6 (Note 1)	V
		-0.5~ $V_{CC} + 0.5$ (Note 2)	
Input diode current	$I_{IK}$	-20	mA
Output diode current	$I_{OK}$	-20 (Note 3)	mA
DC output current	$I_{OUT}$	$\pm 25$	mA
DC $V_{CC}/\text{GND}$ current	$I_{CC}$	$\pm 100$	mA
Power dissipation	$P_D$	150 (Note 4)	mW
Storage temperature	$T_{stg}$	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0\text{V}$

Note 2: High or Low State.

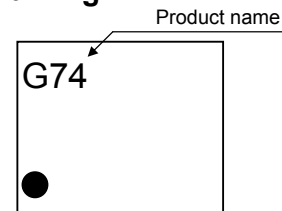
$I_{OUT}$  absolute maximum rating must be observed.

Note 3:  $V_{OUT} < \text{GND}$

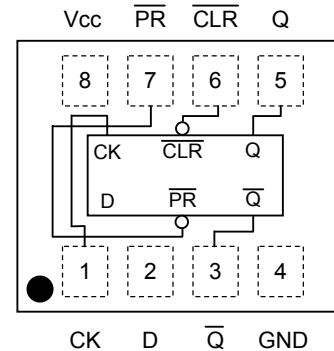
Note 4: Mounted on an FR4 board.

(25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 11.56 mm<sup>2</sup>)

### Marking



### Pin Assignment (top view)

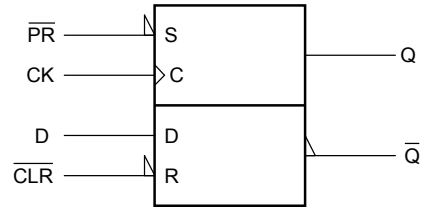


## Truth Table

Inputs				Outputs		Function
$\overline{\text{CLR}}$	$\overline{\text{PR}}$	D	CK	Q	$\overline{\text{Q}}$	
L	H	X	X	L	H	Clear
H	L	X	X	H	L	Preset
L	L	X	X	H	H	—
H	H	L	$\uparrow$	L	H	—
H	H	H	$\uparrow$	H	L	—
H	H	X	$\downarrow$	$\text{Qn}$	$\overline{\text{Qn}}$	No Change

X : Don't Care

## IEC Logic Symbol



**Operating Ranges**

Characteristics	Symbol	Value	Unit
Power supply voltage	$V_{CC}$	0.9~3.6	V
Input voltage	$V_{IN}$	0~5.5	V
Output voltage	$V_{OUT}$	0~3.6 (Note 5)	V
		0~ $V_{CC}$ (Note 6)	
Output Current	$I_{OH}/I_{OL}$	±8.0 (Note 7)	mA
		±4.0 (Note 8)	
		±3.0 (Note 9)	
		±1.7 (Note 10)	
		±0.3 (Note 11)	
		±0.02 (Note 12)	
Operating temperature	$T_{opr}$	-40~85	°C
Input rise and fall time	$dt/dV$	0~10 (Note 13)	ns/V

Note 5:  $V_{CC} = 0V$

Note 6: High or Low state.

Note 7:  $V_{CC} = 3.0\sim 3.6 V$

Note 8:  $V_{CC} = 2.3\sim 2.7 V$

Note 9:  $V_{CC} = 1.65\sim 1.95 V$

Note 10:  $V_{CC} = 1.4\sim 1.6 V$

Note 11:  $V_{CC} = 1.1\sim 1.3 V$

Note 12:  $V_{CC} = 0.9 V$

Note 13:  $V_{IN} = 0.8\sim 2.0 V, V_{CC} = 3.0 V$

**DC Electrical Characteristics**

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit		
			V <sub>CC</sub> (V)	Min	Typ.	Max	Min		Max	
High-level input voltage	V <sub>IH</sub>	—	0.9	V <sub>CC</sub>	—	—	V <sub>CC</sub>	—	V	
			1.1~1.3	V <sub>CC</sub> × 0.7	—	—	V <sub>CC</sub> × 0.7	—		
			1.4~1.6	V <sub>CC</sub> × 0.65	—	—	V <sub>CC</sub> × 0.65	—		
			1.65~1.95	V <sub>CC</sub> × 0.65	—	—	V <sub>CC</sub> × 0.65	—		
			2.3~2.7	1.7	—	—	1.7	—		
			3.0~3.6	2.0	—	—	2.0	—		
Low-level input voltage	V <sub>IL</sub>	—	0.9	—	—	GND	—	GND	V	
			1.1~1.3	—	—	V <sub>CC</sub> × 0.3	—	V <sub>CC</sub> × 0.3		
			1.4~1.6	—	—	V <sub>CC</sub> × 0.35	—	V <sub>CC</sub> × 0.35		
			1.65~1.95	—	—	V <sub>CC</sub> × 0.35	—	V <sub>CC</sub> × 0.35		
			2.3~2.7	—	—	0.7	—	0.7		
			3.0~3.6	—	—	0.8	—	0.8		
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -0.02 mA	0.9	0.75	—	—	0.75	—	V
			I <sub>OH</sub> = -0.3 mA	1.1~1.3	V <sub>CC</sub> × 0.75	—	—	V <sub>CC</sub> × 0.75	—	
			I <sub>OH</sub> = -1.7 mA	1.4~1.6	V <sub>CC</sub> × 0.75	—	—	V <sub>CC</sub> × 0.75	—	
			I <sub>OH</sub> = -3.0 mA	1.65~1.95	V <sub>CC</sub> - 0.45	—	—	V <sub>CC</sub> - 0.45	—	
			I <sub>OH</sub> = -4.0 mA	2.3~2.7	2.0	—	—	2.0	—	
			I <sub>OH</sub> = -8.0 mA	3.0~3.6	2.48	—	—	2.48	—	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 0.02 mA	0.9	—	—	0.1	—	0.1	V
			I <sub>OL</sub> = 0.3 mA	1.1~1.3	—	—	V <sub>CC</sub> × 0.25	—	V <sub>CC</sub> × 0.25	
			I <sub>OL</sub> = 1.7 mA	1.4~1.6	—	—	V <sub>CC</sub> × 0.25	—	V <sub>CC</sub> × 0.25	
			I <sub>OL</sub> = 3.0 mA	1.65~1.95	—	—	0.45	—	0.45	
			I <sub>OL</sub> = 4.0 mA	2.3~2.7	—	—	0.4	—	0.4	
			I <sub>OL</sub> = 8.0 mA	3.0~3.6	—	—	0.4	—	0.4	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5V	0~3.6	—	—	±0.1	—	±1.0	μA	
Power off leakage current	I <sub>OFF</sub>	V <sub>IN</sub> = 0~5.5V V <sub>OUT</sub> = 0~3.6V	0.0	—	—	1.0	—	10.0	μA	
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	3.6	—	—	1.0	—	10.0	μA	

**Timing Requirements ( Input :  $t_r = t_f = 3 \text{ ns}$  )**

Characteristic	Symbol	Test condition	Ta = 25°C			Ta = -40~85°C		Unit	
			V <sub>CC</sub> (V)	Min.	Typ.	Max.	Min.		Max.
Pulse width ( CK )	$t_{W(L)}$ $t_{W(H)}$		0.9	—	26.4	—	—	ns	
			1.1~1.3	12.4	—	—	22.7		—
			1.4~1.6	5.5	—	—	6.7		—
			1.65~ 1.95	4.3	—	—	4.7		—
			2.3~2.7	3.5	—	—	3.5		—
			3.0~3.6	3.2	—	—	3.2		—
Pulse width ( $\overline{\text{CLR}}$ , $\overline{\text{PR}}$ )	$t_{W(L)}$		0.9	—	22.8	—	—	ns	
			1.1~1.3	11.6	—	—	20.4		—
			1.4~1.6	5.3	—	—	6.5		—
			1.65~ 1.95	4.2	—	—	4.6		—
			2.3~2.7	3.3	—	—	3.3		—
			3.0~3.6	3.2	—	—	3.2		—
Set-up time	$t_s$		0.9	—	31.9	—	—	ns	
			1.1~1.3	14.4	—	—	21.7		—
			1.4~1.6	6.4	—	—	7.2		—
			1.65~ 1.95	4.4	—	—	4.8		—
			2.3~2.7	2.5	—	—	2.9		—
			3.0~3.6	1.9	—	—	2.3		—
Hold time	$t_h$		0.9	—	0.5	—	—	ns	
			1.1~1.3	0.1	—	—	0.1		—
			1.4~1.6	0.1	—	—	0.1		—
			1.65~ 1.95	0.1	—	—	0.1		—
			2.3~2.7	0.1	—	—	0.1		—
			3.0~3.6	0.1	—	—	0.1		—
Removal time ( $\overline{\text{CLR}}$ , $\overline{\text{PR}}$ )	$t_{rem}$		0.9	—	17.9	—	—	ns	
			1.1~1.3	8.6	—	—	13		—
			1.4~1.6	3.9	—	—	4.4		—
			1.65~ 1.95	2.6	—	—	3.1		—
			2.3~2.7	1.5	—	—	1.9		—
			3.0~3.6	1.2	—	—	1.5		—

**AC Electrical Characteristics ( Input :  $t_r = t_f = 3 \text{ ns}$  )**

Characteristic	Symbol	Test condition	Ta = 25°C			Ta = -40~85°C		Unit	
			V <sub>CC</sub> (V)	Min.	Typ.	Max.	Min.		Max.
Propagation delay time ( $\overline{\text{CK}} - \overline{\text{Q}}$ , $\overline{\text{Q}}$ )	$t_{\text{pLH}}$ $t_{\text{pHL}}$	CL = 10 pF	0.9	—	36.6	—	1.0	—	ns
			1.1~1.3	—	15.7	23.2	1.0	34.6	
			1.4~1.6	—	8.0	10.5	1.0	11.5	
			1.65~1.95	—	5.9	7.4	1.0	7.9	
			2.3~2.7	—	3.8	4.7	1.0	5.1	
			3.0~3.6	—	3.0	3.8	1.0	4.2	
		CL = 15 pF	0.9	—	40.8	—	1.0	—	
			1.1~1.3	—	17.1	25.3	1.0	38.5	
			1.4~1.6	—	8.8	11.5	1.0	12.7	
			1.65~1.95	—	6.4	8.1	1.0	8.6	
			2.3~2.7	—	4.1	5.1	1.0	5.5	
			3.0~3.6	—	3.3	4.1	1.0	4.5	
		CL = 30 pF	0.9	—	54.8	—	1.0	—	
			1.1~1.3	—	22.6	34.7	1.0	54.4	
			1.4~1.6	—	11.4	15.0	1.0	16.8	
			1.65~1.95	—	8.2	10.3	1.0	10.8	
			2.3~2.7	—	5.2	6.3	1.0	6.6	
			3.0~3.6	—	4.1	5.0	1.0	5.3	
Propagation delay time ( $\overline{\text{CLR}}$ , $\overline{\text{PR}} - \overline{\text{Q}}$ , $\overline{\text{Q}}$ )	$t_{\text{pLH}}$ $t_{\text{pHL}}$	CL = 10 pF	0.9	—	46.9	—	1.0	—	ns
			1.1~1.3	—	18.8	27.8	1.0	45.2	
			1.4~1.6	—	9.5	12.4	1.0	14.0	
			1.65~1.95	—	6.9	8.7	1.0	9.1	
			2.3~2.7	—	4.3	5.3	1.0	5.7	
			3.0~3.6	—	3.3	4.2	1.0	4.6	
		CL = 15 pF	0.9	—	50.1	—	1.0	—	
			1.1~1.3	—	20.2	29.8	1.0	49.4	
			1.4~1.6	—	10.1	13.2	1.0	15.1	
			1.65~1.95	—	7.3	9.2	1.0	9.7	
			2.3~2.7	—	4.5	5.6	1.0	6.2	
			3.0~3.6	—	3.6	4.5	1.0	4.9	
		CL = 30 pF	0.9	—	64.4	—	1.0	—	
			1.1~1.3	—	25.6	39.2	1.0	64.6	
			1.4~1.6	—	12.6	16.8	1.0	19.1	
			1.65~1.95	—	9.0	11.3	1.0	11.8	
			2.3~2.7	—	5.6	6.8	1.0	7.1	
			3.0~3.6	—	4.4	5.3	1.0	5.6	

## AC Electrical Characteristics ( Input : $t_r = t_f = 3 \text{ ns}$ )

Characteristic	Symbol	Test condition	Ta = 25°C			Ta = -40~85°C		Unit
			V <sub>CC</sub> (V)	Min.	Typ.	Max.	Min.	
Clock frequency	f <sub>MAX</sub>	CL = 10 pF	0.9	—	14	—	—	MHz
			1.1~1.3	22	35	—	14	
			1.4~1.6	57	75	—	51	
			1.65~1.95	90	111	—	84	
			2.3~2.7	169	194	—	145	
			3.0~3.6	233	254	—	200	
		CL = 15 pF	0.9	—	13	—	—	
			1.1~1.3	20	32	—	13	
			1.4~1.6	59	74	—	48	
			1.65~1.95	84	104	—	80	
			2.3~2.7	156	179	—	139	
			3.0~3.6	225	246	—	189	
		CL = 30 pF	0.9	—	14	—	—	
			1.1~1.3	17	30	—	11	
			1.4~1.6	45	63	—	39	
			1.65~1.95	71	91	—	68	
			2.3~2.7	135	159	—	120	
			3.0~3.6	189	214	—	163	
Input capacitance	C <sub>IN</sub>	—	3.6	—	3	—	—	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 14)	0.9~3.6	—	14	—	—	pF

Note 14 : C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

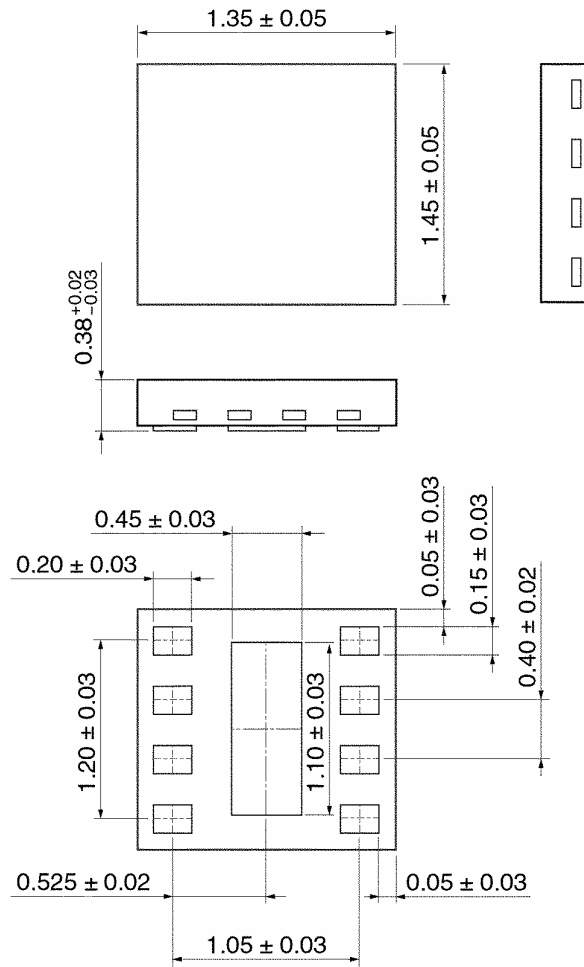
Average operating current can be obtained by the equation:

$$I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

## Package Dimensions

CSON8-P-0.4

Unit: mm



Weight : 0.002 g (Typ.)



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20070701-EN GENERAL

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